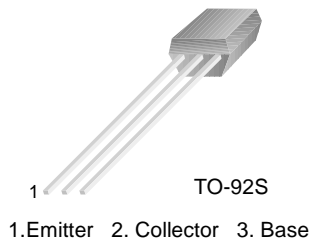


KSA1378

KSA1378

Low Frequency Power Amplifier

- Collector Power Dissipation : $P_C = 300\text{mW}$
- Complement to KSC3488



PNP Epitaxial Silicon Transistor

Absolute Maximum Ratings $T_a = 25^\circ\text{C}$ unless otherwise noted

| Symbol | Parameter | Ratings | Units |
|-----------|-----------------------------|-----------|------------------|
| V_{CBO} | Collector-Base Voltage | -30 | V |
| V_{CEO} | Collector-Emitter Voltage | -25 | V |
| V_{EBO} | Emitter-Base Voltage | -5 | V |
| I_C | Collector Current (DC) | -300 | mA |
| I_{CP} | * Collector Current (Pulse) | -500 | mA |
| P_C | Collector Power Dissipation | 300 | mW |
| T_J | Junction Temperature | 150 | $^\circ\text{C}$ |
| T_{STG} | Storage Temperature | -55 ~ 150 | $^\circ\text{C}$ |

* $PW \leq 10\text{ms}$, Duty cycle $\leq 50\%$

Electrical Characteristics $T_a = 25^\circ\text{C}$ unless otherwise noted

| Symbol | Parameter | Test Condition | Min. | Typ. | Max. | Units |
|----------------------|--|--|------|-------|------|-------|
| BV_{CBO} | Collector-Base Breakdown Voltage | $I_C = -100\mu\text{A}$, $I_E = 0$ | -30 | | | V |
| BV_{CEO} | Collector-Emitter Breakdown Voltage | $I_C = -10\text{mA}$, $I_B = 0$ | -25 | | | V |
| BV_{EBO} | Emitter-Base Breakdown Voltage | $I_E = -10\mu\text{A}$, $I_C = 0$ | -5 | | | nA |
| I_{CBO} | Collector Cut-off Current | $V_{CB} = -25\text{V}$, $I_E = 0$ | | | -100 | mA |
| I_{EBO} | Emitter Cut-off Current | $V_{EB} = -3\text{V}$, $I_C = 0$ | | | -100 | nA |
| h_{FE} | * DC Current Gain | $V_{CE} = -1\text{V}$, $I_C = -50\text{mA}$ | 70 | | 400 | |
| $V_{CE}(\text{sat})$ | * Collector-Emitter Saturation Voltage | $I_C = -300\text{mA}$, $I_B = -30\text{mA}$ | | -0.35 | -0.6 | V |

* Pulse Test: $PW \leq 350\mu\text{s}$, Duty cycle $\leq 2\%$

h_{FE} Classification

| Classification | O | Y | G |
|----------------|----------|-----------|-----------|
| h_{FE} | 70 ~ 140 | 120 ~ 240 | 200 ~ 400 |

Typical Characteristics

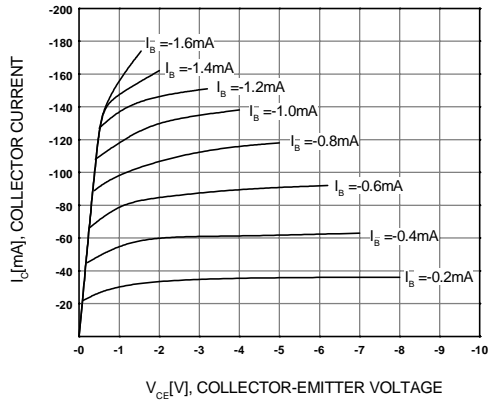


Figure 1. Static Characteristic

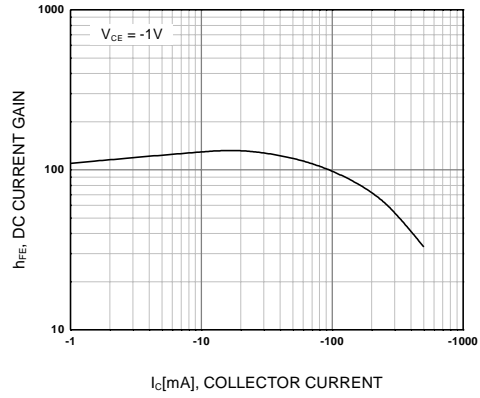


Figure 2. DC current Gain

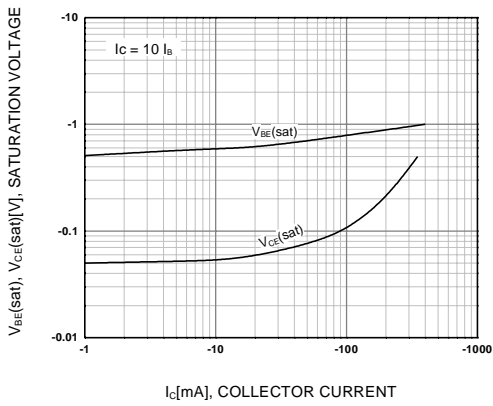


Figure 3. Base-Emitter Saturation Voltage
Collector-Emitter Saturation Voltage

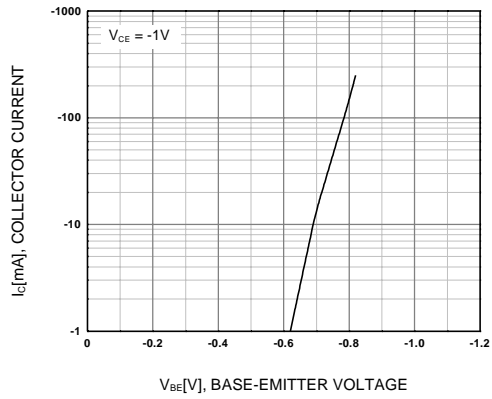


Figure 4. Base-Emitter On Voltage

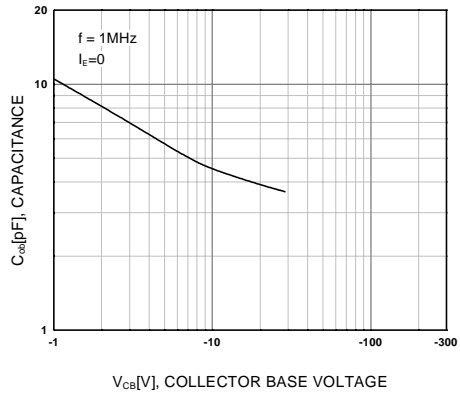
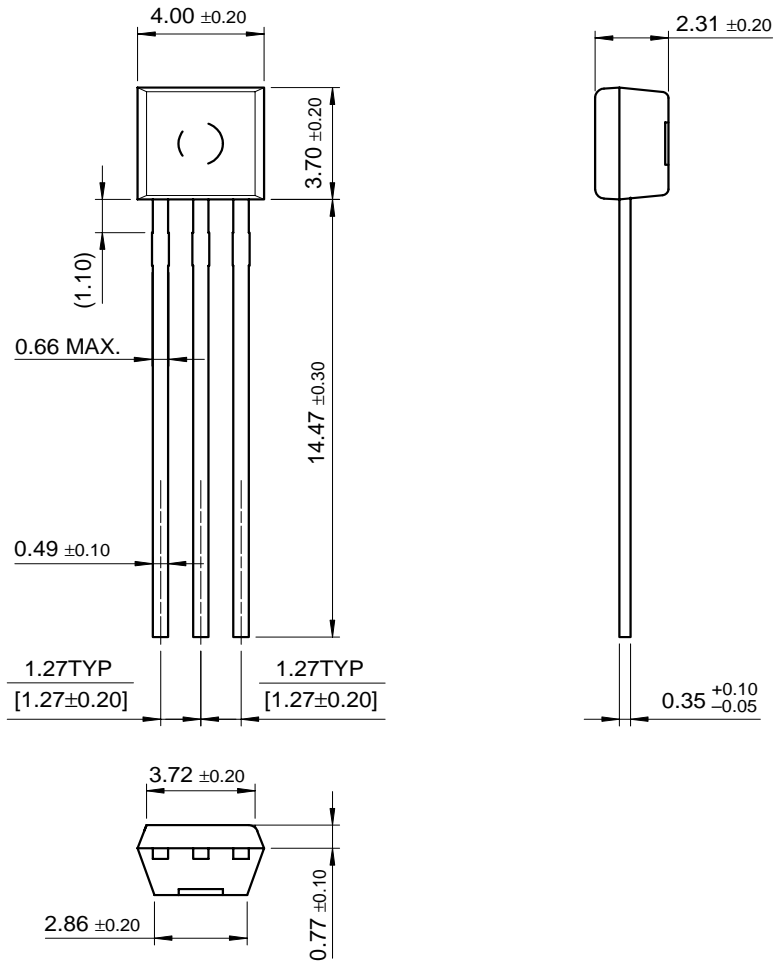


Figure 5. Collector Output Capacitance

Package Dimensions

TO-92S



Dimensions in Millimeters

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